

2.495V Programmable Shunt Voltage Reference

DESCRIPTION

TS431 integrated circuits are three-terminal programmable shunt regulator diodes. These monolithic IC voltage references operate as a low temperature coefficient zener which is programmable from V_{REF} to 36V with two external resistors. These devices exhibit a wide operating current range to 250mA with a typical dynamic impedance of 0.2 Ω . The characteristics of these references make them excellent replacements for zener diodes in many applications such as digital voltmeters, power supplies, and op amp circuitry. The 2.495V reference makes it convenient to obtain a stable reference from 5.0V logic supplies, and since The TS431 operates as a shunt regulator, it can be used as either a positive or negative stage reference.

FEATURES

- Programmable Output Voltage up to 36V
 - TS431A – V_{REF} 2.495V $\pm 1\%$ tolerance
 - TS431B – V_{REF} 2.495V $\pm 0.5\%$ tolerance
- Fast Turn-On Response
- Sink Current Capability: 120mA
- Low Dynamic Output Impedance: 0.2 Ω (Typ.)
- Min. Operating Cathode Current: 0.2mA (Typ.)
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATION

- SMPS
- Lighting
- Telecommunication
- Home appliance



SOT-23

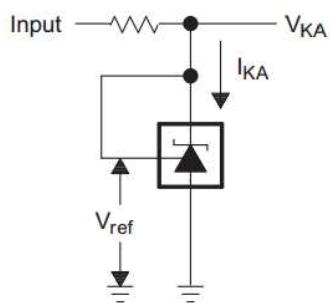


Pin Definition:

1. Cathode
2. Reference
3. Anode

Notes: MSL 3 (Moisture Sensitivity Level) per J-STD-020

SIMPLIFIED SCHEMATIC



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Cathode Voltage	V_{KA}	36	V
Continuous Cathode Current	I_K	120	mA
Reference Input Current	I_{REF}	10	mA
Power Dissipation	P_D	0.25	W
Operating Temperature Range	T_{OPER}	-40 ~ +125	$^\circ\text{C}$
Junction Temperature	T_J	+150	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-40 ~ +150	$^\circ\text{C}$

THERMAL PERFORMANCE			
PARAMETER	SYMBOL	LIMIT	UNIT
Thermal Resistance - Junction to Case	$R_{\Theta JC}$	110	$^\circ\text{C}/\text{W}$
Thermal Resistance - Junction to Ambient	$R_{\Theta JA}$	350	$^\circ\text{C}/\text{W}$

Note: Consider measured with the PCB copper area of approximately 1 in² (Multi-Layer)

ELECTRICAL SPECIFICATIONS ($T_A=+25^\circ\text{C}$, unless otherwise specified)								
PARAMETER	SYMBOL	CONDITIONS		MIN	Typ	MAX	UNIT	
Reference voltage	V_{REF}	$V_{KA} = V_{REF}, I_K = 10\text{mA}$ (Figure 1)	TS431A	2.470	2.495	2.520	V	
			TS431B	2.483		2.507		
Deviation of reference input voltage	ΔV_{REF}	$V_{KA} = V_{REF}, I_K = 10\text{mA}$ (Figure 1) $T_A = -20 \sim 85^\circ\text{C}$		--	25	35	mV	
Ratio of change in Vref to change in cathode Voltage	$\Delta V_{REF} / \Delta V_{KA}$	$I_{KA} = 10\text{mA}$, (Figure 2)	$V_{KA} = 10\text{V}$ to V_{REF}	--	-1.2	-2.0	mV/V	
Reference Input current	I_{REF}	$R1 = 10\text{k}\Omega, R2 = \infty$ $I_{KA} = 10\text{mA}$ (Figure 2)		--	1.5	3.5	μA	
				--	0.4	1.2		
Deviation of reference input current, over temp.	ΔI_{REF}	$R1 = 10\text{k}\Omega, R2 = \infty, I_{KA} = 10\text{mA}$ $T_A = -20 \sim 85^\circ\text{C}$ (Figure 2)		--	0.1	1.0	μA	
Off-state Cathode Current	I_{KA} (off)	$V_{REF} = 0\text{V}$ (Figure 3), $V_{KA} = 36\text{V}$		--	0.2	0.5	Ω	
Dynamic Output Impedance	$ Z_{KA} $	$f < 1\text{kHz}, V_{KA} = V_{REF}$ (Figure 1)		--	0.2	0.5	Ω	
Minimum operating cathode current	I_{KA} (min)	$V_{KA} = V_{REF}$ (Figure 1)		--	0.2	0.5	mA	

Note: The deviation parameters ΔV_{REF} and ΔI_{REF} are defined as difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TS431ARIX-Z RFG	SOT-23	3,000pcs / 7" Reel
TS431BRIX-Z RFG	SOT-23	3,000pcs / 7" Reel

CHARACTERISTICS CURVES

($T_C = 25^\circ\text{C}$ unless otherwise noted)

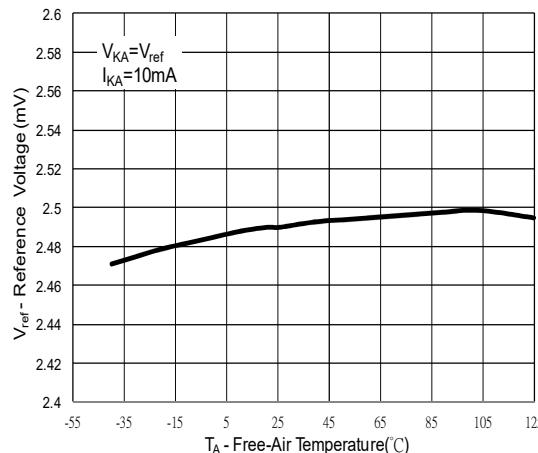


Figure 1. V_{REF} vs. Ambient Temperature

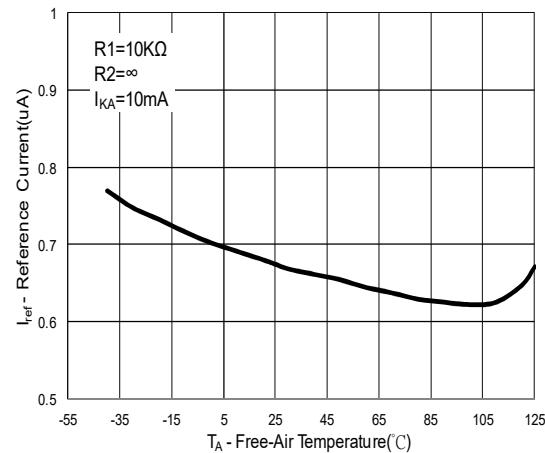


Figure 2. I_{REF} vs. Ambient Temperature

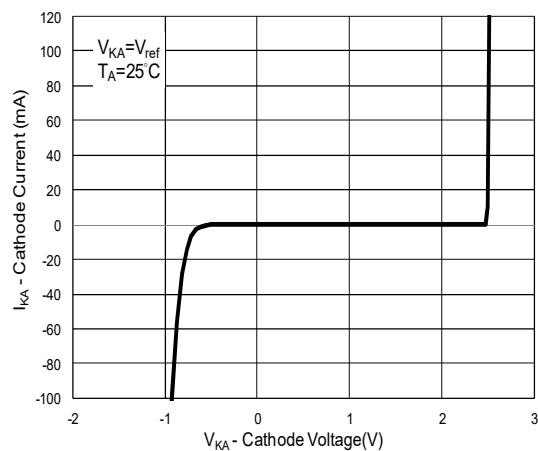


Figure 3. Cathode Current vs. Cathode Voltage

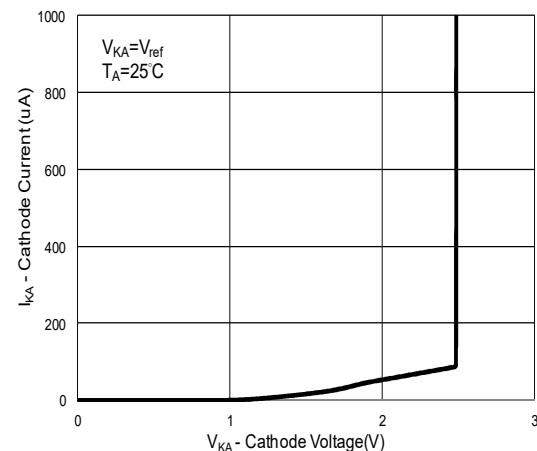


Figure 4. Cathode Current vs. Cathode Voltage

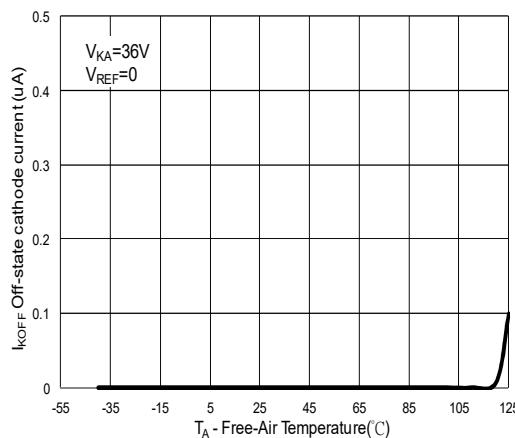


Figure 5. Off-State Cathode current vs. Ambient Temperature

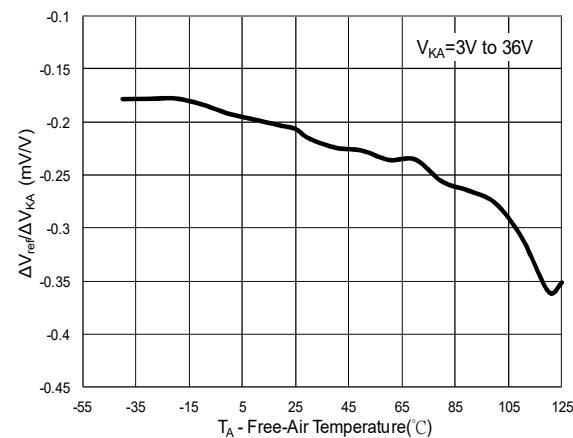
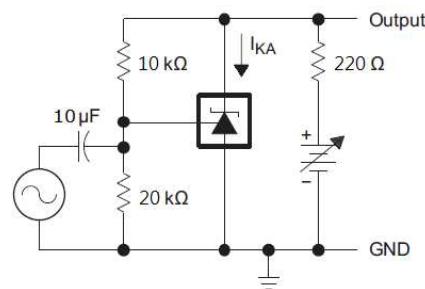
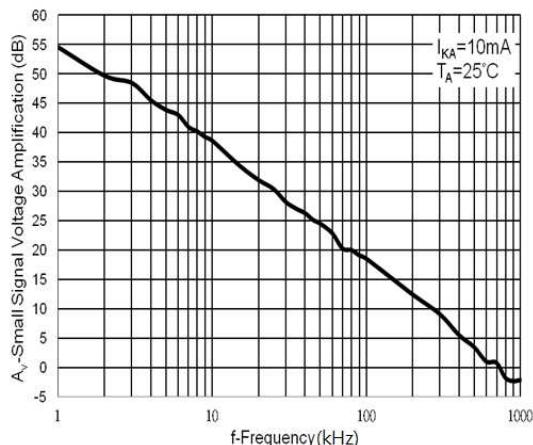


Figure 6. Ratio of delta reference voltage to delta cathode voltage vs. Ambient Temperature

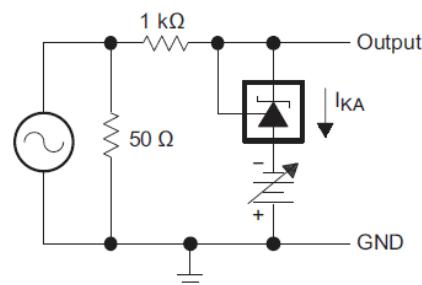
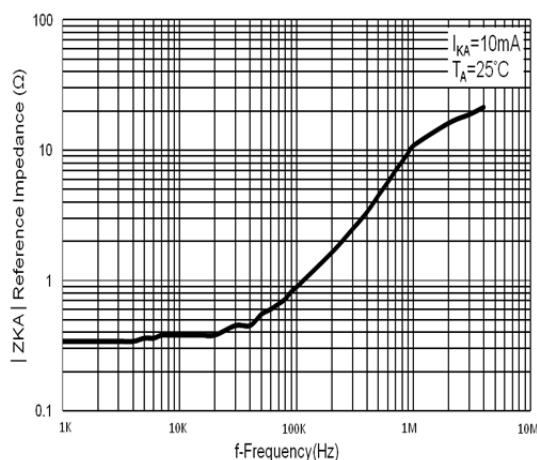
TYPICAL PERFORMANCE CHARACTERISTICS

Small-Signal Voltage Gain and Phase Shift vs. Frequency



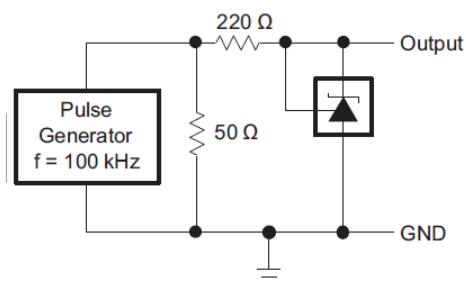
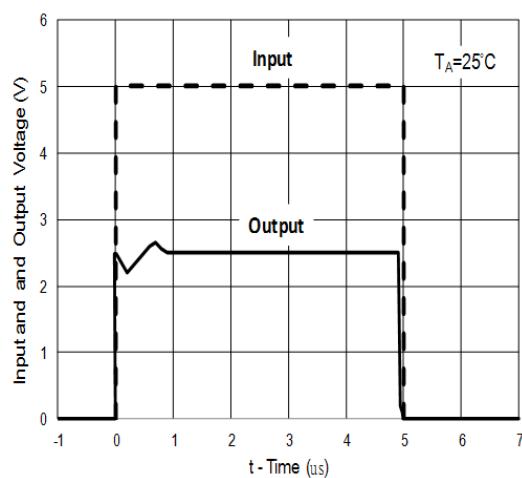
Test Circuit For Voltage Amplification.

Reference Impedance vs. Frequency



Test Circuit For Reference Impedance.

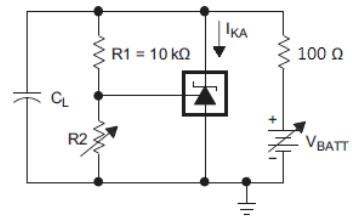
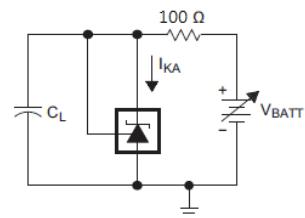
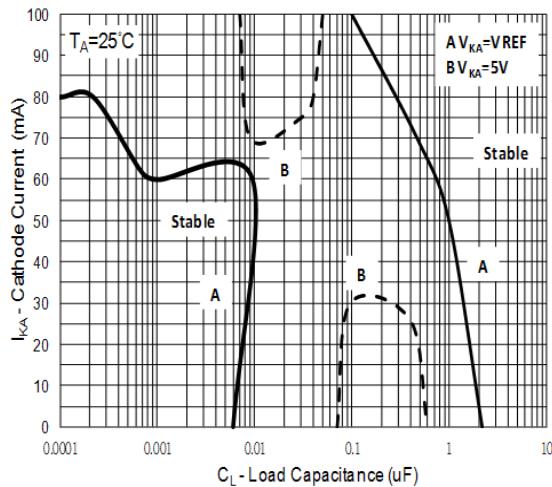
Pulse Response

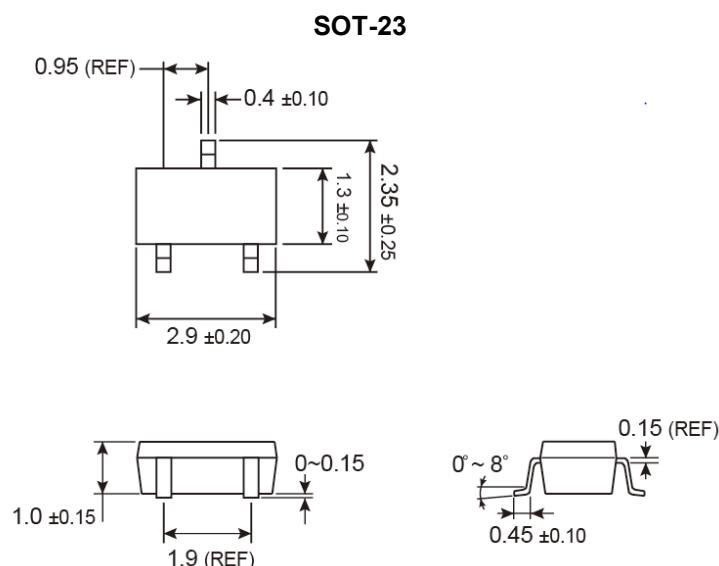
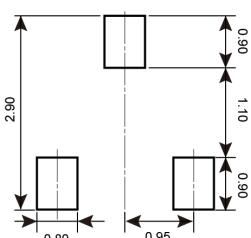
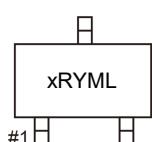


Test Circuit For Pulse Response.

TYPICAL PERFORMANCE CHARACTERISTICS

Stability Boundary Condition



PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

SUGGESTED PAD LAYOUT (Unit: Millimeters)

MARKING DIAGRAM


xR = Device code
A = TS431A
B = TS431B
Y = Year Code
M = Month Code for Halogen Free Product
 O = Jan P = Feb Q = Mar R = Apr
 S = May T = Jun U = Jul V = Aug
 W = Sep X = Oct Y = Nov Z = Dec
L = Lot Code (1~9, A~Z)

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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